

MBR1060, MBR1080, MBR1090, MBR10100

MBR1060 and MBR10100 are Preferred Devices

SWITCHMODE™ Power Rectifiers

This series of SWITCHMODE power rectifiers uses the Schottky Barrier principle with a platinum barrier metal. These state-of-the-art devices have the following features:

Features

- Guard-Ring for Stress Protection
- Low Forward Voltage
- 175°C Operating Junction Temperature
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Low Power Loss/High Efficiency
- High Surge Capacity
- Low Stored Charge Majority Carrier Conduction
- Pb-Free Packages are Available*

Mechanical Characteristics

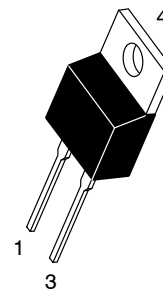
- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds



ON Semiconductor®

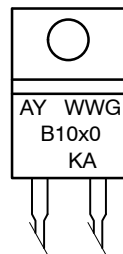
<http://onsemi.com>

SCHOTTKY BARRIER RECTIFIERS 10 AMPERES, 60 to 100 VOLTS



**TO-220AC
CASE 221B
PLASTIC**

MARKING DIAGRAM



A = Assembly Location
Y = Year
WW = Work Week
G = Pb-Free Package
B10x0 = Device Code
x = 6, 8, 9 or 10
KA = Diode Polarity

ORDERING INFORMATION

| Device | Package | Shipping |
|-----------|---------------------|---------------|
| MBR1060 | TO-220 | 50 Units/Rail |
| MBR1060G | TO-220 (Pb-Free) | 50 Units/Rail |
| MBR1080 | TO-220 | 50 Units/Rail |
| MBR1080G | TO-220 (Pb-Free) | 50 Units/Rail |
| MBR1090 | TO-220 | 50 Units/Rail |
| MBR1090G | TO-220 (Pb-Free) | 50 Units/Rail |
| MBR10100 | TO-220 | 50 Units/Rail |
| MBR10100G | TO-220 (Pb-Free) | 50 Units/Rail |

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Preferred devices are recommended choices for future use and best overall value.

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MAXIMUM RATINGS

| Rating | Symbol | MBR | | | | Unit |
|--|---------------------------------|--------------|------|------|-------|------------------|
| | | 1060 | 1080 | 1090 | 10100 | |
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V_{RRM} V_{RWM} V_R | 60 | 80 | 90 | 100 | V |
| Average Rectified Forward Current (Rated V_R) $T_C = 133^\circ\text{C}$ | $I_{F(AV)}$ | 10 | | | | A |
| Peak Repetitive Forward Current (Rated V_R , Square Wave, 20 kHz) $T_C = 133^\circ\text{C}$ | I_{FRM} | 20 | | | | A |
| Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz) | I_{FSM} | 150 | | | | A |
| Peak Repetitive Reverse Surge Current (2.0 μs , 1.0 kHz) | I_{RRM} | 0.5 | | | | A |
| Operating Junction Temperature (Note 1) | T_J | - 65 to +175 | | | | $^\circ\text{C}$ |
| Storage Temperature | T_{stg} | - 65 to +175 | | | | $^\circ\text{C}$ |
| Voltage Rate of Change (Rated V_R) | dv/dt | 10,000 | | | | V/ μs |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

THERMAL CHARACTERISTICS

| | | | |
|---|-----------------|-----|--------------------|
| Maximum Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 2.0 | $^\circ\text{C/W}$ |
| Maximum Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 60 | $^\circ\text{C/W}$ |

ELECTRICAL CHARACTERISTICS

| | | | |
|--|-------|----------------------------|----|
| Maximum Instantaneous Forward Voltage (Note 2) ($i_F = 10$ Amps, $T_C = 125^\circ\text{C}$) ($i_F = 10$ Amps, $T_C = 25^\circ\text{C}$) ($i_F = 20$ Amps, $T_C = 125^\circ\text{C}$) ($i_F = 20$ Amps, $T_C = 25^\circ\text{C}$) | v_F | 0.7 0.8 0.85 0.95 | V |
| Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, $T_C = 125^\circ\text{C}$) (Rated dc Voltage, $T_C = 125^\circ\text{C}$ – MBR1060 only) (Rated dc Voltage, $T_C = 25^\circ\text{C}$) | i_R | 6.0 15 0.10 | mA |

2. Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2.0\%$.

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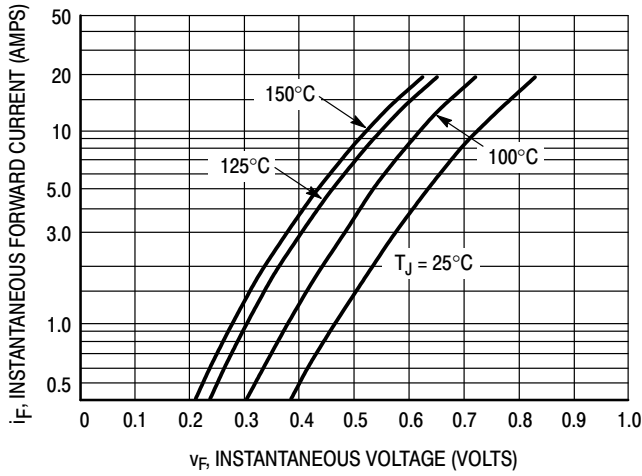


Figure 1. Typical Forward Voltage

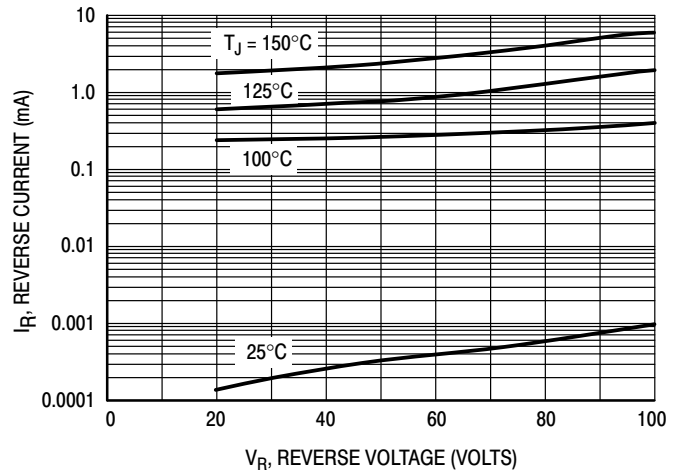


Figure 2. Typical Reverse Current

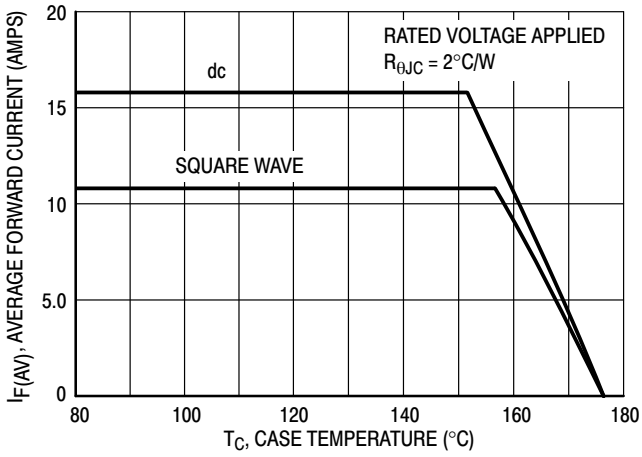


Figure 3. Typical Current Derating, Case

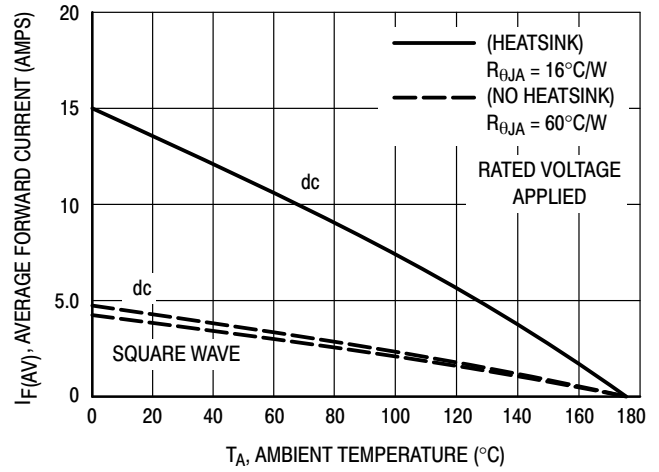


Figure 4. Typical Current Derating, Ambient

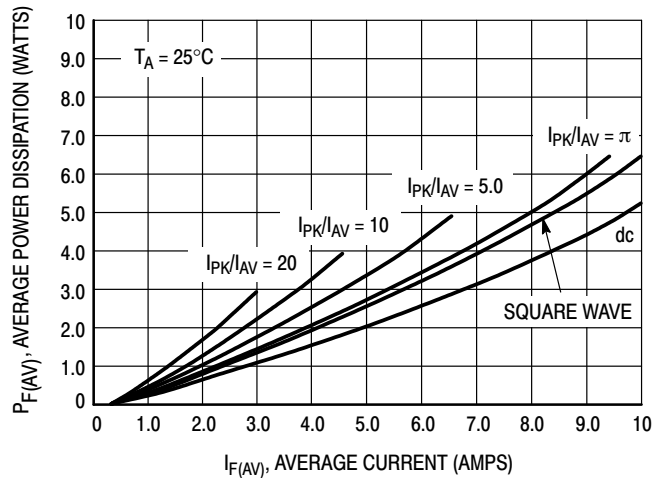
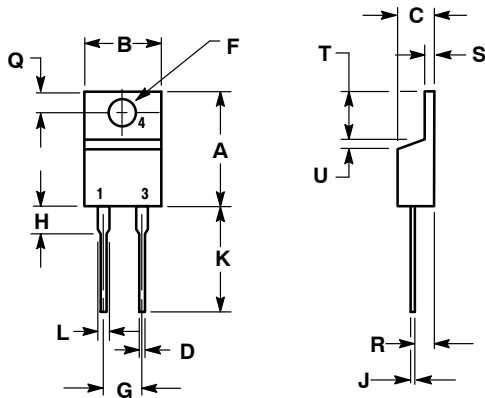


Figure 5. Forward Power Dissipation

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PACKAGE DIMENSIONS

TO-220
CASE 221B-04
ISSUE E




NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

| DIM | INCHES | | MILLIMETERS | |
|-----|--------|-------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | 0.595 | 0.620 | 15.11 | 15.75 |
| B | 0.380 | 0.405 | 9.65 | 10.29 |
| C | 0.160 | 0.190 | 4.06 | 4.82 |
| D | 0.025 | 0.035 | 0.64 | 0.89 |
| F | 0.142 | 0.161 | 3.61 | 4.09 |
| G | 0.190 | 0.210 | 4.83 | 5.33 |
| H | 0.110 | 0.130 | 2.79 | 3.30 |
| J | 0.014 | 0.025 | 0.36 | 0.64 |
| K | 0.500 | 0.562 | 12.70 | 14.27 |
| L | 0.045 | 0.060 | 1.14 | 1.52 |
| Q | 0.100 | 0.120 | 2.54 | 3.04 |
| R | 0.080 | 0.110 | 2.04 | 2.79 |
| S | 0.045 | 0.055 | 1.14 | 1.39 |
| T | 0.235 | 0.255 | 5.97 | 6.48 |
| U | 0.000 | 0.050 | 0.000 | 1.27 |

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